

TO-5 HERMETIC CAN PACKAGE ACTIVE AREA $=10.00 \mathrm{~mm}^{2}$

## FEATURES

- High speed
- Low capacitance
- Blue enhanced
- Low dark current


## DESCRIPTION

The PDB-C106 is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a hermetic TO-5 metal can with a flat window.

## APPLICATIONS

- Instrumentation
- Analytical measurements
- Laser sensor
- Industrial sensor

ABSOLUTE MAXIMUM RATING (TA $=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | MAX | UNITS |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {BR }}$ | Reverse Voltage |  | 100 | V |
| $\mathrm{~T}_{\text {sta }}$ | Storage Temperature | -55 | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\circ}$ | Operating Temperature Range | -40 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{Ts}_{\mathrm{s}}$ | Soldering Temperature |  | +240 | ${ }^{*}$ |
| $\mathrm{I}_{\mathrm{L}}$ | Light Current |  | 500 | mA |

*1/16 inch from case for 3 secs max

SPECTRALRESPONSE



WAVELENGTH(nm)

ELECTRO-OPTICAL CHARACTERISTICS (TA=25 ${ }^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | CHARACTERISTIC | TESTCONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| Isc | Short Circuit Current | $\mathrm{H}=100 \mathrm{fc}, 2850 \mathrm{~K}$ | 100 | 130 |  | $\mu \mu \mathrm{~A}$ |
| ID | Dark Current | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V}$ |  | 2 | 10 | nA |
| RsH | Shunt Resistance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ | 200 | 650 |  | $\mathrm{M} \Omega$ |
| TC RsH | RSH Temp. Coefficient | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ |  | -8 |  | $\% /{ }^{\circ} \mathrm{C}$ |
| C | Junction Capacitance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V}^{* *}$ |  | 70 |  | pF |
| $\lambda$ range | Spectral Application Range | Spot Scan | 350 |  | 1100 | nm |
| $\lambda \mathrm{p}$ | Spectral Response - Peak | Spot Scan |  | 950 |  | nm |
| $\mathrm{~V}_{\mathrm{BR}}$ | Breakdown Voltage | $\mathrm{I}=10 \mu \mathrm{~A}$ | 75 | 100 |  | V |
| NEP | Noise Equivalent Power | $\mathrm{V}_{\mathrm{R}}=10 \mathrm{~V} @$ Peak |  | $3 \times 10^{-14}$ |  | $\mathrm{~W} / \sqrt{\mathrm{Hz}}$ |
| tr | Response Time | $\mathrm{RL}=1 \mathrm{~K} \Omega \mathrm{~V}_{\mathrm{R}}=50 \mathrm{~V}$ |  | 18 |  | nS |

Information inthistechnical datasheet is believed to be correctand reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications aresubjecttochangewithoutnotice.** $\mathrm{f}=1 \mathrm{MHz}$
[FORM NO. 100-PDB-C106 REV C]

